

74ALCX16240

Low-Voltage 16-Bit Inverting Buffer/Line Driver with 5V Tolerant Inputs and Outputs

General Description

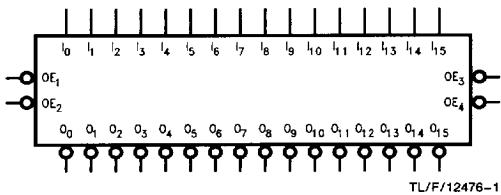
The ALCX16240 contains sixteen inverting buffers with TRI-STATE® outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate TRI-STATE control inputs which can be shorted together for full 16-bit operation.

The ALCX family of devices excel in bus interface applications where very high speeds and low power consumption are required. ALCX devices are capable of interfacing to the latest high-speed busses while consuming less than 20 μ A of quiescent current. In keeping with National's CROSS-VOLT™ philosophy, ALCX inputs and outputs are 5V tolerant allowing them to interface to both 3V and 5V components. ALCX inputs and outputs also power up/down in the high impedance state, facilitating power management and live insertion system features. Bus hold on all input, and control pins removes the need for power-hungry pull-up resistors on TRI-STATE busses. ± 24 mA output drive means ALCX devices can drive all but the heaviest bus and backplane loads quietly due to National's patented Quiet Series™ circuitry.

Features

- 3.6 ns t_{PD} max, 20 μ A I_{CCQ} max
- 5V tolerant inputs and outputs
- Power up/down high impedance inputs and outputs
- Supports live insertion/withdrawal
- Supports power management
- 2.0V–3.6V V_{CC} supply operation
- ± 24 mA output drive
- Bus hold
- Implements patented Quiet Series noise/EMI reduction circuitry
- Functionally compatible with the 74 series 16240
- Latch-up performance exceeds 500 mA
- ESD performance:
Human body model > 2000V
Machine model > 200V

Logic Symbol

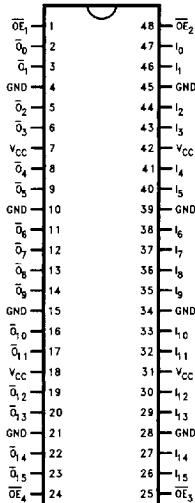


Pin Names	Description
OE _n	Output Enable Inputs (Active Low)
I ₀ –I ₁₅	Inputs
Ø ₀ –Ø ₁₅	Outputs

	SSOP	TSSOP
Order Number	74ALCX16240MEA 74ALCX16240MEAX	74ALCX16240MTD 74ALCX16240MTDX
See NS Package Number	MS48A	MTD48

Connection Diagram

Pin Assignment for SSOP and TSSOP



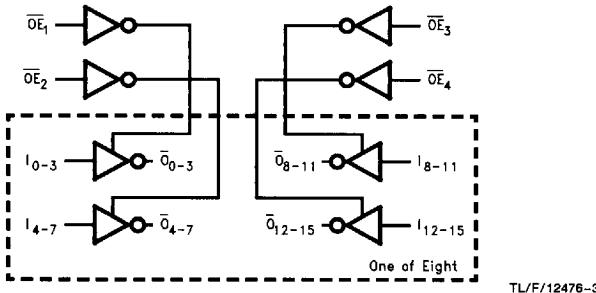
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Functional Description

The ALCX16240 contains sixteen inverting buffers with TRI-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The TRI-STATE out-

puts are controlled by an Output Enable (\bar{OE}_n) input for each nibble. When \bar{OE}_n is LOW, the outputs are in 2-state mode. When \bar{OE}_n is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



Truth Tables

Inputs		Outputs
\bar{OE}_1	I_0-I_3	$\bar{O}_0-\bar{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
\bar{OE}_2	I_4-I_7	$\bar{O}_4-\bar{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
\bar{OE}_3	I_8-I_{11}	$\bar{O}_8-\bar{O}_{11}$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
\bar{OE}_4	$I_{12}-I_{15}$	$\bar{O}_{12}-\bar{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = High Voltage Level

L = Low Voltage Level

X = Immaterial

Z = High Impedance

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Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
V _I	DC Input Voltage	-0.5 to +7.0		V
V _O	DC Output Voltage	-0.5 to +7.0	Output in TRI-STATE	V
		-0.5 to V _{CC} + 0.5	Output in High or Low State (Note 2)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
I _O	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units
V _{CC}	Supply Voltage	2.0	3.6	V
	Operating Data Retention	1.5	3.6	
V _I	Input Voltage	0	5.5	V
V _O	Output Voltage	0	V _{CC} 5.5	V
I _{OH} /I _{OL}	Output Current	V _{CC} = 3.0V ~ 3.6V V _{CC} = 2.7V	±24 ±12	mA
T _A	Free-Air Operating Temperature	-40	85	°C
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V~2.0V, V _{CC} = 3.0V	0	10	ns/V

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40°C to +85°C		Units
				Min	Max	
V _{IH}	HIGH Level Input Voltage		2.7~3.6	2.0		V
V _{IL}	LOW Level Input Voltage		2.7~3.6		0.8	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2		V
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		V
		I _{OH} = -24 mA	3.0	2.2		V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7~3.6		0.2	V
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	V
		I _{OL} = 24 mA	3.0		0.55	V
I _I	Input Leakage Current	Inputs	V _I = 0V or 5.5V	2.7~3.6	±5.0	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40°C to +85°C		Units
				Min	Max	
I _I (HOLD)	Bushold Leakage Current	V _I = 0.8V V _I = 2.0V	3.0	-75	75	μA
I _I (OD)	Bushold Overdrive Current		3.0	±500		μA
I _{OZ}	TRI-STATE Output Leakage	0 ≤ V _O ≤ 5.5V V _I = V _{IH} or V _{IL}	2.7–3.6		±5.0	μA
I _{OFF}	Power-Off Leakage Current	0 ≤ V _I , V _O ≤ 5.5V	0		10	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	2.7–3.6		20	μA
		3.6V ≤ V _I , V _O ≤ 5.5V	2.7–3.6		±20	μA
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} – 0.6V	2.7–3.6		500	μA

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C	Units
				Typical	
V _{O LP}	Quiet Output Dynamic Peak V _{OL}	C _L = 50 pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
V _{O LV}	Quiet Output Dynamic Valley V _{OL}	C _L = 50 pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	V _{CC} = Open, V _I = 0V or V _{CC}	7	pF
C _O	Output Capacitance	V _{CC} = 3.3V, V _I = 0V or V _{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V _{CC} = 3.3V, V _I = 0V or V _{CC} , F = 10 MHz	20	pF

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